NSN 5961-01-123-2432

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-123-2432 **Inclosure Material:** Metal **Overall Diameter:** 0.300 inches **End Application:** 4920-01-054-8588 e/i fscm 81755 **Mounting Facility Quantity: Mounting Method:** Press fit and threaded stud **Features Provided:** Hermetically sealed case Thread Size: 0.250 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 60.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 4.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 10.00 milliamperes source cutoff current **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** voltage **Test Data Document:** 12436-6010351 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unc **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:**